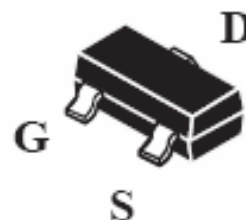


Small Signal MOSFET (P-Channel)

Features

- Low on-resistance: 10Ω
- Low input-capacitance: 30pF
- Low output capacitance: 10pF
- Low threshold: 2.0V
- Fast switching speed: 2.5ns
- RoHS Compliance



SOT-23

HALOGEN
FREE



Application

- DC to DC Converter
- Cellular & PCMCIA Card
- Cordless Telephone
- Power Management in Portable and Battery etc.

Mechanical Data

Case:	SOT-23, Plastic Package
Terminals:	Solderable per MIL-STD-202G, Method 208
Weight:	0.008 gram

Maximum Ratings *(T_{Ambient}=25°C unless noted otherwise)*

Symbol	Description	BSS84	Unit	Conditions
V_{DSS}	Drain-Source Voltage	50	V	
V_{GSS}	Gate-Source Voltage	±20	V	
I_D	Drain Current Continuous	130	mA	T _A =25 °C
I_{DM}	Drain Current Pulsed	520	mA	t _p ≤10μS
P_D	Power Dissipation	225	mW	T _A =25 °C
R_{thJA}	Max. Thermal Resistance, Junction to Ambient	556	° C/W	
T_J, T_{STG}	Operation Junction and Storage Temperature Range	-55 to +150	° C	

Small Signal MOSFET (P-Channel)

BSS84

Electrical Characteristics ($T_{Ambient}=25^{\circ}C$ unless noted otherwise)

Static Characteristics (Note 1)

Symbol	Description	Min.	Typ.	Max.	Unit	Conditions
V(BR)DSS	Drain-Source Breakdown Voltage	50	-	-	V	$V_{GS}=0V, I_D=250\mu A$
V_{GS(th)}	Gate-Source Threshold Voltage	0.8	-	2.0	V	$V_{DS}=V_{GS}, I_D=1mA$
I_{GSS}	Gate-Source Leakage Current	-	-	± 60	μA	$V_{DS}=0V, V_{GS}=\pm 20V$
I_{DSS}	Zero Gate Voltage Drain Current	-	-	0.1	μA	$V_{DS}=25V, V_{GS}=0V$
		-	-	15	μA	$V_{DS}=50V, V_{GS}=0V$
R_{DS(ON)}	Drain-Source ON Resistance	-	5.0	10	Ω	$V_{GS}=5V, I_D=100mA$
g_{FS}	Forward Transconductance	50	-	-	mS	$V_{DS}=25V, I_D=100mA, f=1KHz$

Dynamic Characteristics

Symbol	Description	Min.	Typ.	Max.	Unit	Conditions
C_{iss}	Input Capacitance	-	30	-	pF	$V_{DS}=5V, V_{GS}=0V, f=1MHz$
C_{rss}	Reverse Transfer Capacitance	-	5.0	-		
C_{oss}	Output Capacitance	-	10	-		

Switching Characteristics (Note 2)

Symbol	Description	Min.	Typ.	Max.	Unit	Conditions
t_{on}	Turn-On Time	-	25	-	nS	$V_{DD}=-15V, R_L=50\Omega, I_D=-2.5A$
t_r	Rise-Time	-	1.0	-		
t_{off}	Turn-Off Time	-	16	-		
t_f	Fall-Time	-	8.0	-		
Q_T	Gate Charge	-	6000	-	PC	

Small Signal MOSFET (P-Channel)

BSS84

Source-Drain Diode Characteristics

Symbol	Description	Min.	Typ.	Max.	Unit	Conditions
I_S	Continuous Drain-Source Diode Forward Current	-	-	0.13	A	
I_{SM}	Pulsed Drain-Source Diode Forward Current	-	-	0.52	A	
V_{SD}	Source-Drain Forward Voltage (Note 2)	-	2.5	-	V	

Note: 1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%

2. Switching Time is Essentially Independent of Operation Temperature.

Typical Characteristics Curves

Fig.1- Transfer Characteristics

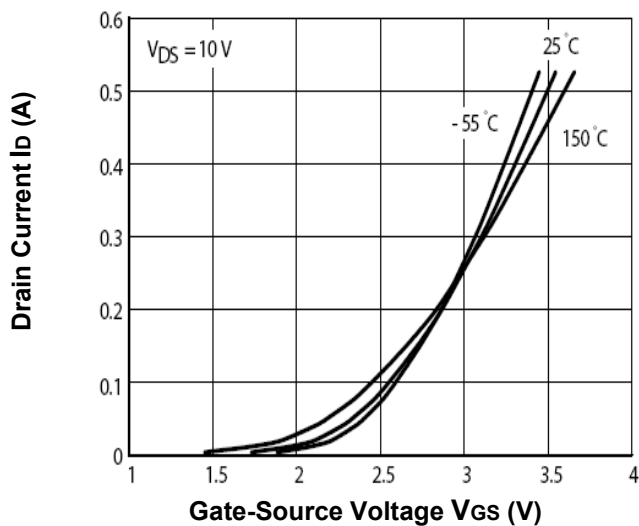


Fig.2- On Region Characteristics

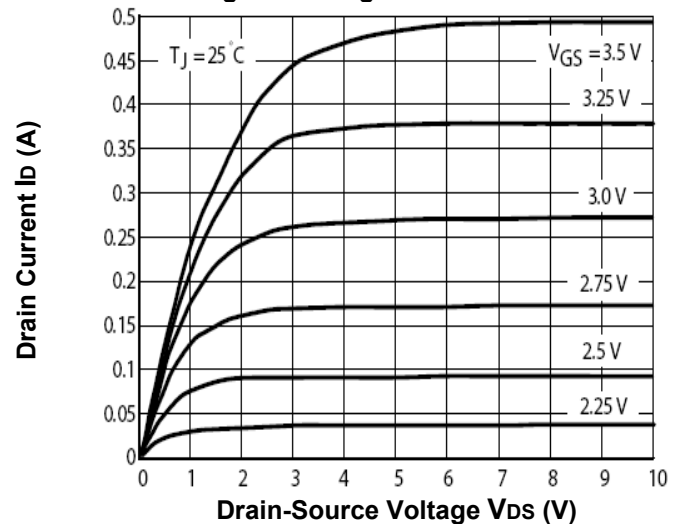


Fig.3- On-Resistance vs. Drain Current

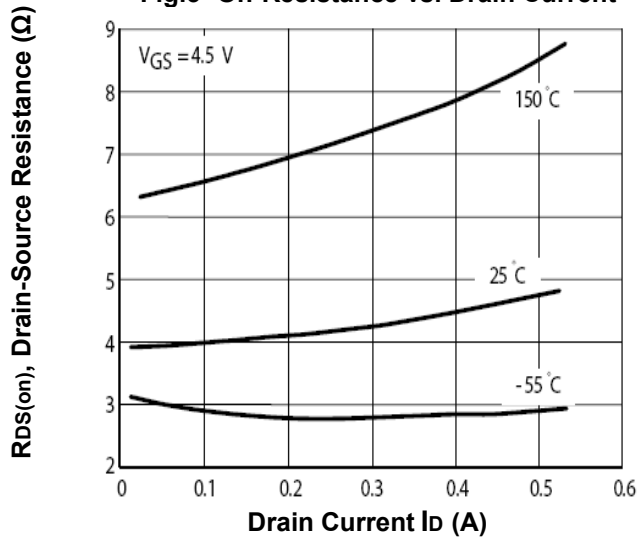


Fig.4- On-Resistance vs. Drain Current

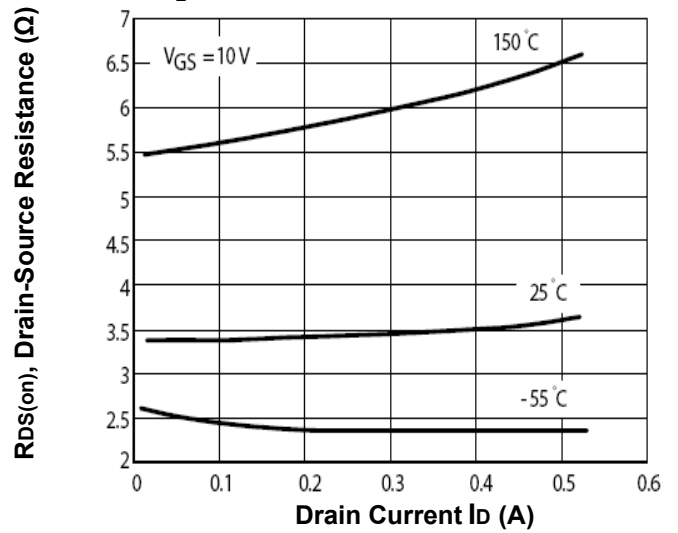


Fig.5- On-Resistance Variation with Temperature

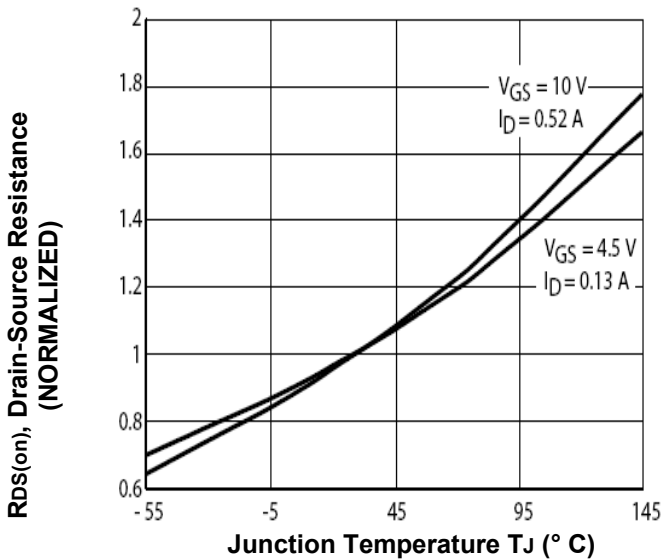


Fig.6- Gate Charge

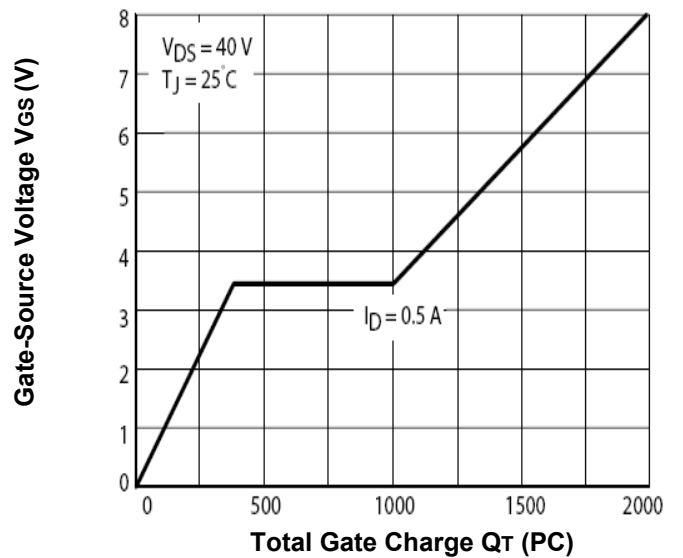
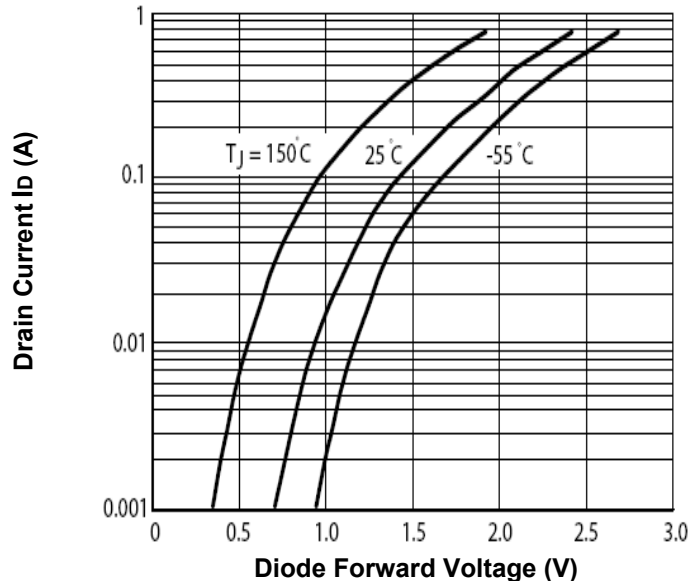
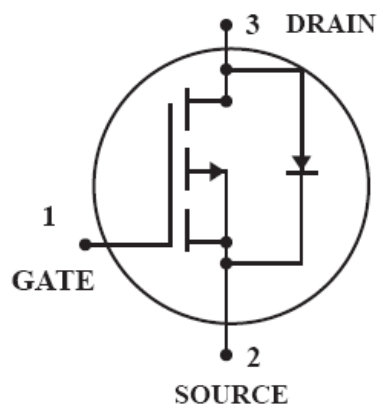


Fig.7- Body Diode Forward Voltage



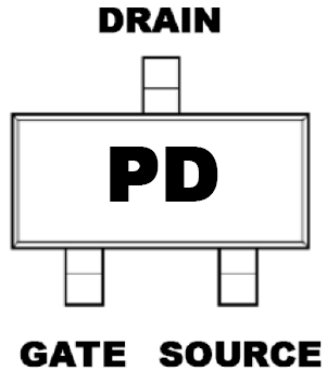
Equivalent Circuit



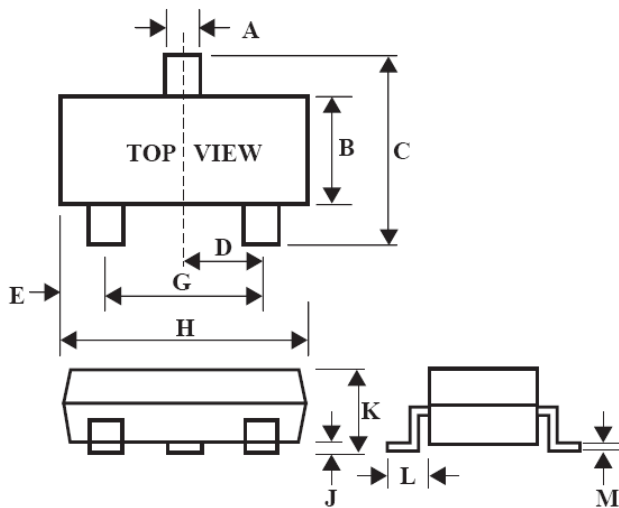
Small Signal MOSFET (P-Channel)

BSS84

Marking Information:



Dimensions in mm



SOT-23		
Dim	Min	Max
A	0.35	0.51
B	1.19	1.40
C	2.10	3.00
D	0.85	1.05
E	0.46	1.00
G	1.70	2.10
H	2.70	3.10
J	0.01	0.13
K	0.89	1.10
L	0.30	0.61
M	0.076	0.25

SOT-23

How to contact us:

US HEADQUARTERS

28040 WEST HARRISON PARKWAY, VALENCIA, CA 91355-4162

Tel: (800) TAITRON (800) 824-8766 (661) 257-6060

Fax: (800) TAITFAX (800) 824-8329 (661) 257-6415

Email: taitron@taitroncomponents.com

Http://www.taitroncomponents.com

TAITRON COMPONENTS MEXICO, S.A .DE C.V.

BOULEVARD CENTRAL 5000 INTERIOR 5 PARQUE INDUSTRIAL ATITALAQUIA, HIDALGO C.P.
42970 MEXICO

Tel: +52-55-5560-1519

Fax: +52-55-5560-2190

TAITRON COMPONENTS INCORPORATED REPRESENTAÇÕES DO BRASIL LTDA

RUA DOMINGOS DE MORAIS, 2777, 2.ANDAR, SALA 24 SAÚDE - SÃO PAULO-SP 04035-001 BRAZIL

Tel: +55-11-5574-7949

Fax: +55-11-5572-0052

TAITRON COMPONENTS INCORPORATED, SHANGHAI REPRESENTATIVE OFFICE

METROBANK PLAZA, 1160 WEST YAN' AN ROAD, SUITE 1503, SHANGHAI, 200052, CHINA

Tel: +86-21-5424-9942

Fax: +86-21-5424-9931

www.s-manuals.com